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February 2001

FDS3890

80V N-Channel Dual PowerTrench[®] MOSFET

General Description

SEMICONDUCTOR IM

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers.

These MOSFETs feature faster switching and lower gate charge than other MOSFETs with comparable $R_{_{\text{DS(ON)}}}$ specifications. The result is a MOSFET that is easy and safer to drive (even at very high frequencies), and DC/DC power supply designs with higher overall efficiency.

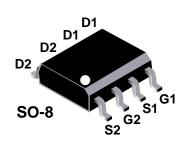
Features

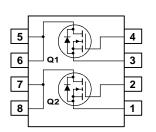
4.7 A, 80 V.

$$R_{DS(ON)} = 44 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$$

 $R_{DS(ON)} = 50 \text{ m}\Omega @ V_{GS} = 6 \text{ V}$

- · Fast switching speed
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Unit
V _{DSS}	Drain-Source Voltage		80	V
V _{GSS}	Gate-Source Voltage		± 20	V
I _D	Drain Current – Continuous	(Note 1a)	4.7	A
	– Pulsed		20	
P _D	Power Dissipation for Dual Operation		2	W
	Power Dissipation for Single Operation	(Note 1a)	1.6	
		(Note 1b)	1.0	
		(Note 1c)	0.9	
Γ _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +175	°C
Therma	I Characteristics			
R _{θJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _{eJC}	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W

Device Marking	Device	Reel Size	Tape width	Quantity
FDS3890	FDS3890	13"	12mm	2500 units

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Electrical Characteristics $T_{A} = 25^{\circ}C$ unless otherwise noted Symbol Min Units Parameter **Test Conditions** Тур Max Drain-Source Avalanche Ratings (Note 2) W_{DSS} Single Pulse Drain-Source $V_{DD} = 40 \text{ V}, \text{ I}_{D} = 4.7 \text{ A}$ 175 mJ Avalanche Energy Maximum Drain-Source Avalanche I_{AR} 4.7 А Current **Off Characteristics** $\mathsf{BV}_{\mathsf{DSS}}$ Drain-Source Breakdown Voltage $V_{GS} = 0 V, I_D = 250 \mu A$ 80 V ΔBV_{DSS} Breakdown Voltage Temperature $I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$ 86 mV/°C $\Delta T_{\rm J}$ Coefficient Zero Gate Voltage Drain Current I_{DSS} $V_{DS} = 64 V_{.}$ $V_{GS} = 0 V$ 1 μA Gate-Body Leakage, Forward $V_{GS} = 20 V$, $V_{DS} = 0 V$ 100 nA IGSSF $V_{GS} = -20 V$ $V_{DS} = 0 V$ I_{GSSR} Gate-Body Leakage, Reverse -100 nA **On Characteristics** (Note 2) V V_{GS(th)} Gate Threshold Voltage $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ 2 2.3 4 Gate Threshold Voltage $I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$ $\Delta V_{GS(th)}$ -6 mV/°C ΔT_{J} **Temperature Coefficient** R_{DS(on)} Static Drain-Source $V_{GS} = 10 V.$ $I_{D} = 4.7 \text{ A}$ 34 44 mΩ **On-Resistance** $V_{GS} = 6.0 V_{.}$ $I_{D} = 4.4 \text{ A}$ 37 50 V_{GS} = 10 V, I_D = 4.7 A, T_J = 125°C 60 82 On-State Drain Current $V_{GS} = 10 V$, $V_{DS} = 5 V$ 20 А I_{D(on)} s Forward Transconductance $V_{DS} = 10 V$, $I_{D} = 4.7 \text{ A}$ 24 **g**_{FS} **Dynamic Characteristics** Input Capacitance 1180 pF C_{iss} $V_{DS} = 40 V$, $V_{GS} = 0 V$, Coss **Output Capacitance** f = 1.0 MHz 171 pF C_{rss} **Reverse Transfer Capacitance** 50 pF Switching Characteristics (Note 2) Turn-On Delay Time 11 20 $V_{DD} = 40 V$, $I_{D} = 1 A$, ns t_{d(on)} $V_{GS} = 10 V$, $R_{GEN} = 6 \Omega$ Turn–On Rise Time 8 16 ns tr Turn-Off Delay Time 26 50 t_{d(off)} ns Turn-Off Fall Time 12 25 tf ns Qq **Total Gate Charge** $V_{DS} = 40 V$, $I_{D} = 4.7 A$, 25 35 nC $V_{GS} = 10 V$ Q_{gs} Gate-Source Charge 4.5 nC 5.8 nC Q_{qd} Gate-Drain Charge Drain–Source Diode Characteristics and Maximum Ratings Maximum Continuous Drain-Source Diode Forward Current I_{S} 1.3 А Drain–Source Diode Forward

Notes:

 V_{SD}

1. R_{0.A} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

 $V_{GS} = 0 V$, $I_{S} = 1.3 A$



Voltage

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%



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b) 125°C/W when mounted on a .04 in² pad of 2 oz copper

(Note 2)

c) 135°C/W when mounted on a minimum pad.

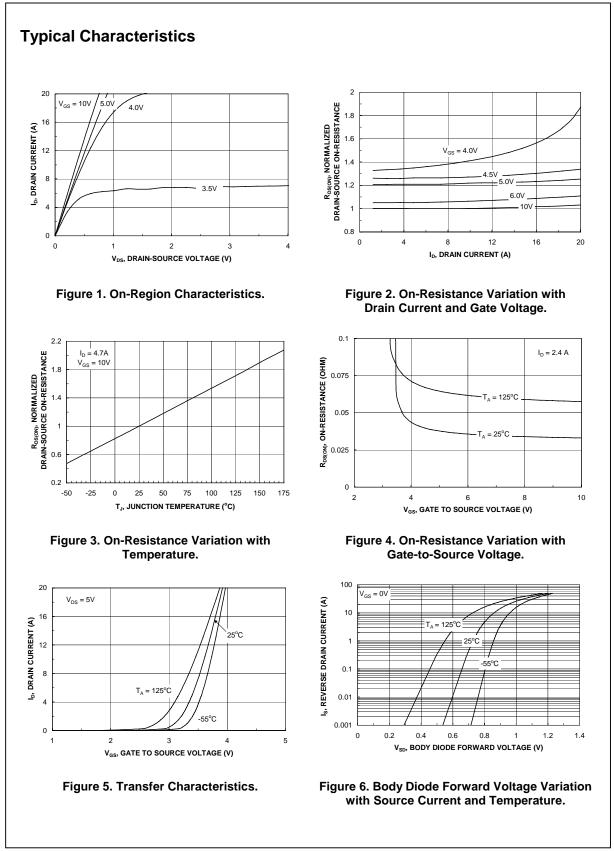
0.74

1.2

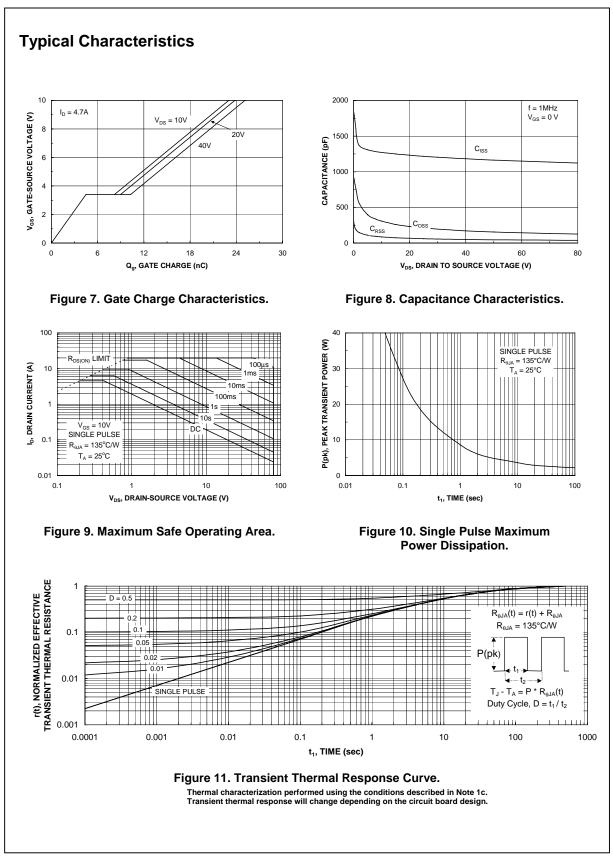
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FDS3890 Rev B(W)

FDS3890



FDS3890



FDS3890

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